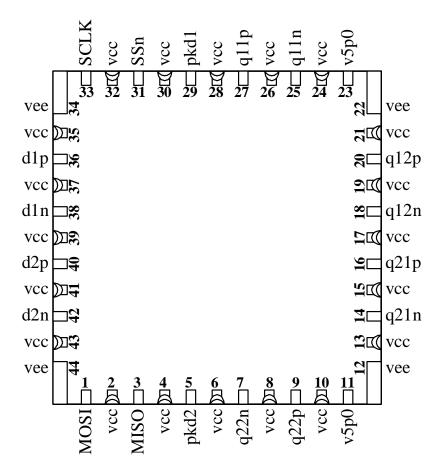
ASNT6153-KHM Dual 2-Channel CTLE with Peak Detectors

- High-speed adjustable linear equalizer
- Two independent data channels with two independent equalization paths per channel
- Independently adjustable 5 zeros and 2 poles in each path AC response
- Independent gain adjustment in each equalization path
- High-speed CMOS 3-wire interface for chip control
- Input peak detectors in both channels
- Fully differential CML-type analog input and output interfaces
- Two power supplies for the data paths and AC control circuitry
- Average power consumption: 1.8W
- Fabricated in SiGe for high performance, yield, and reliability
- Limited temperature variation over industrial temperature range
- Die size $1.5 \times 1.5 mm^2$
- Custom CQFN 44-pin package



DESCRIPTION

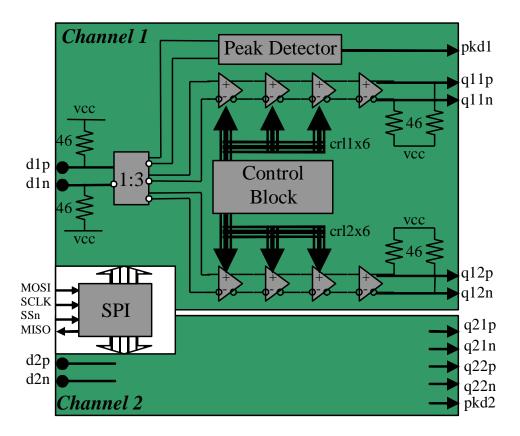


Fig. 1. Functional Block Diagram

The IC shown in Fig. 1 is a two-path adjustable continuous-time linear equalizer (CTLE) with two independently controlled analog data equalization channels per path. Each equalization channel has its own output. The AC response of each path has 6 controls: adjustable DC gain, 3 independently adjustable zeros, and 2 independently adjustable poles.

Input Peak Detectors that represent the input signal amplitude are added to each channel.

The part's I/Os support CML-type differential interface with on-chip 46*Ohm* termination to VCC. Matching external terminations are also required.

All operational modes of the chip are controlled by a Control Block that communicates with an external computer through a high-speed 3-wire serial interface. Data paths 1 and 2 are named Group A and Group B in the corresponding graphical user interface (GUI).

The part operates with a positive supply vcc = +3.3V for the main data paths, and an additional positive supply v5p0 = +5.0V for the AC control circuitry. The negative supply rail vee should be connected to external ground as shown in Fig. 2a.

The part can also operate with a negative supply $\mathbf{vee} = -3.3V$ for the main data paths, and an additional positive supply $\mathbf{v5p0} = +1.7V$ for the AC control circuitry. In this case the positive



supply rail vcc should be connected to external ground as shown in Fig. 2b. Also, the SPI input and output signals should be connected through DC blocks, or optocouplers.

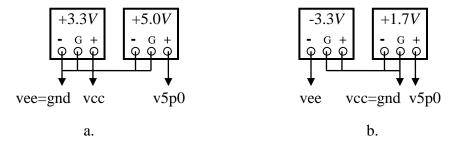


Fig. 2. Power Supply Configurations: Positive (a) and Negative (b)

Equalization Path

Typical AC responses of an Equalization Path are shown in Fig. 3.

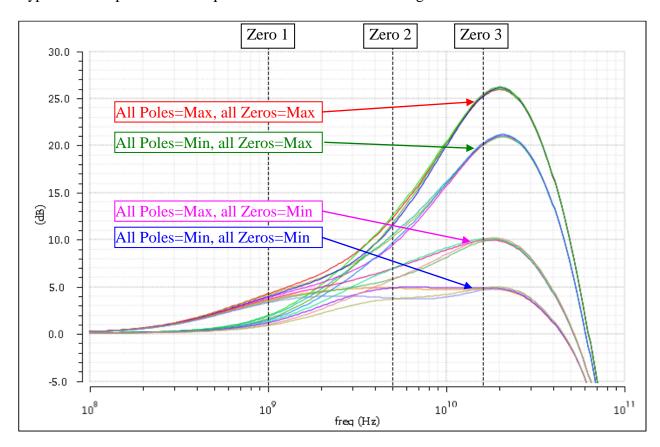


Fig. 3. Typical AC responses of an Equalization Path

Each path has 3 independent adjustable Zeros, and two independent adjustable Poles. For each setting, the DC gain can be adjusted between -3dB and +5dB.

Additionally, the path's bandwidth (BW) can be also adjusted using EF controls as shown by the red and magenta curves in Fig. 4 that are plotted for the Max Pole, and Min Zero setting.

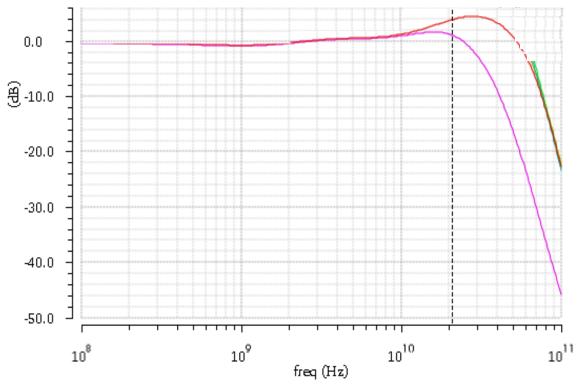


Fig. 4. DC Gain and BW Control Characteristics

Corresponding controls are detailed in Table 1. Increase of any control results in gain increase within a certain frequency range around the specified frequency as shown in the corresponding drawings.

Control	Frequency,	SPI	GUI	Corresponding
function	GHz	name	Slider name	drawing
Low-frequency zero	1	zcl_X	Zero at f / Lo	Fig. 3
Mid-frequency zero	5	zcm_X	Zero at f / M	Fig. 3
High-frequency zero	16	zch_X	Zero at f / Hi	Fig. 3
First pole	2	pc1_X	Pole / 1	Fig. 3
Second pole	16	pc2_X	Pole / 2	Fig. 3
Gain	DC	gc_X	Gain	
Output EF	>20	efcX	Out BW	Fig. 4
Input EF	>20	efc12	Input BW	Fig. 4

Table 1. Data Channel Controls

Here X is the channel (or output) number that equals to 1 or 2. In the GUI, X=1 corresponds to Channel1 in Group A, or Channel 3 in Group B, and X=2 corresponds to Channel2 in Group A, or Channel 4 in Group B.

Peak Detector

The Peak Detector block represents the single-ended swing of its input signal as an output voltage between 1.65V to 2.85V. The typical characteristics for a 1GHz sinusoidal input signal at different PT operational conditions are shown in Fig. 5.

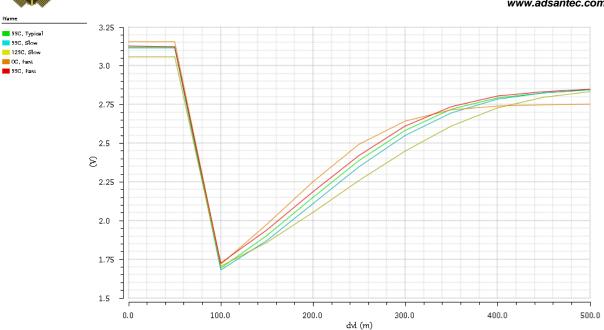


Fig. 5. Peak Detector Typical Simulated Characteristics for Different To and Process Corners

As can be seen in the plot, the signal swings below a certain value are represented by the high voltage above 3.0V. This function can be used as an indication of NO Input Signal (Loss-of-signal, or LOS). The LOS threshold can be adjusted as desired.

The Peak Detector features a short settling time as shown in Fig. 6 that shows the sinusoidal input signal, and the Peak Detector output at different operational conditions.

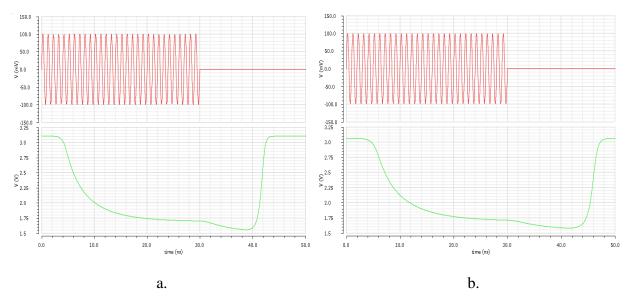


Fig. 6. Peak Detector settling Time (a – Nominal, b – Worst Case Slow)

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3-Wire Interface

All functions of the chip are controlled through a 3-wire SPI. The interface includes a 16-byte internal register and operates with 3.3V CMOS signals. It provides control signals for any of 2 groups of channels: Group A (Channels 1 and 2), and Group B (Channels 3 and 4). Each group data can be loaded independently, and the active group is selected by bit1 of byte16 in each data packet. The bit map of the interface is shown in Table 2, and its timing diagram in Fig. 7.

Table 2. 3-Wire Interface Bit Map

Byte	Bit	Bit	Signal	Default	Signal function	
#	#	order	name	Value		
1	From 7	MSB	zcl_1	10000000	Low-frequency zero control for the first output	
	to 0	LSB	201_1 10000000		of the selected Group	
2	From 7	MSB	zcm_1 10000000		Middle-frequency zero control for the first	
	to 0	LSB	Zem_1	1000000	output of the selected Group	
3	From 7	MSB	zch_1	01000000	High-frequency zero control for the first output	
3	to 0	LSB	ZCII_I	01000000	of the selected Group	
4	From 7	MSB	go 1	10000000	Gain control for the first output of the selected	
4	to 0	LSB	gc_1	1000000	Group	
_	From 7	MSB	ma1 1	10000000	First pole control for the first output of the	
5	to 0	LSB	pc1_1	10000000	selected Group	
	From 7	MSB	0 1	10000000	Second pole control for the first output of the	
6	to 0	LSB	pc2_1	10000000	selected Group	
	From 7	MSB	C 1	10000000	BW control for the first output of the selected	
7	to 0	LSB	efc1		Group	
	From 7	MSB		10000000	Low-frequency zero control for the second	
8	to 0	LSB	zcl_2		output of the selected Group	
	From 7	MSB		10000000	Middle-frequency zero control for the second	
9	to 0	LSB	zcm_2		output of the selected Group	
1.0	From 7	MSB		0.1.0.0.0.0.0	High-frequency zero control for the second	
10	to 0	LSB	zch_2	01000000	output of the selected Group	
	From 7	MSB	gc_2 10000000		Gain control for the second output of the	
11	to 0	LSB			selected Group	
	From 7	MSB			First pole control for the second output of the	
12	to 0	LSB	pc1_2	10000000	selected Group	
	From 7	MSB			Second pole control for the second output of	
13	to 0	LSB	pc2_2	10000000	the selected Group	
	From 7	MSB			BW control for the second output of the	
14	to 0	LSB	efc2	10000000	selected Group	
	From 7				selected Group	
15	to 0	LSB	losth1	10000000	LOL threshold control for the selected Group	
	From 7	MSB			Additional BW control for both outputs of the	
	-		efc12	100000	selected Group	
16	to 2 LSB		0	"0"- write to Group A, "1"- write to Group B		
	0	wraddr 0		0	Constant "0"	
	U		-	U	Constant o	



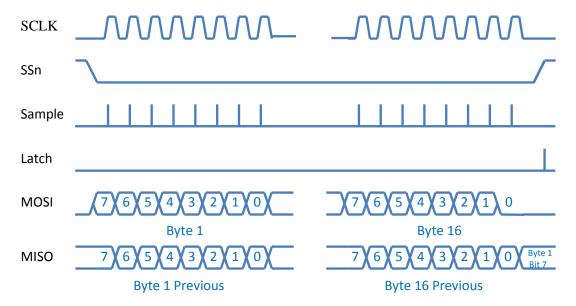


Fig. 7. SPI Timing Diagram

The initial registers of the SPI are preset to the above default states at the time of the chip power supply activation.

TERMINAL FUNCTIONS

TERMINAL		MINAL	Description			
Name	No.	Type				
	High-Speed I/Os					
d1p	36	CML-type	Differential high-speed channel 1 data inputs with internal SE 46Ohm			
d1n	38	Analog	termination to VCC			
d2p	40	Inputs	Differential high-speed channel 2 data inputs with internal SE 46Ohm			
d2n	42		termination to VCC			
q11p	27	CML-type	Differential high-speed channel 1 path 1 data outputs with internal SE			
q11n	25	Analog	46Ohm termination to vcc			
q12p	20	Outputs	Differential high-speed channel 1 path 2 data outputs with internal SE			
q12n	18		46Ohm termination to vcc			
q21p	16		Differential high-speed channel 2 path 1 data outputs with internal SE			
q21n	14		46Ohm termination to vcc			
q22p	9		Differential high-speed channel 2 path 2 data outputs with internal SE			
q22n	7		46Ohm termination to vcc			
	Low-Speed I/Os					
SSn	31	3.3 <i>V</i>	3-wire interface enable input with internal 474KOhm pull-up to vcc			
SCLK	33	CMOS	3-wire interface clock input with internal 474KOhm pull-down to vee			
MOSI	1	I/Os	3-wire interface data input with internal 474KOhm pull-down to vee			
MISO	3		3-wire interface data output			
pkd1	29	CMOS	Error Detector output and below-threshold signal amplitude indicator,			
pkd2	5	Output	with internal 6KOhm SE termination to vcc			



Supply And Termination Voltages				
Name	Description	Pin Number		
v5p0	+5.0 <i>V</i> positive power supply Negative pin to vee	11, 23		
vee	Ground	12, 22, 34, 44		
vcc	+3.3 <i>V</i> positive power supply Negative pin to vee	2, 4, 6, 8, 10, 13, 15, 17, 19, 21, 24, 26, 28, 30, 32, 35, 37, 39, 41, 43		

ELECTRICAL CHARACTERISTICS

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS
General Parameters					
vee		0.0		V	External ground
vcc	3.1	3.3	3.5	V	vcc in relation to vee
v5p0	4.8	5.0	5.3	V	v5p0 in relation to vee
$I_{\rm v5p0}$ per eq. channel	3.5		28	mA	Depending on the state of
$I_{ m vcc}$	300		600	mA	SPI control bytes
Power Consumption	1.0	1.8	2.6	W	
vcc ramp speed			10	ms	For reliable SPI preset
Junction temperature	0	50	125	$^{\circ}C$	
	Data i	nput (d	1p/d1n, c	d2p/d2n)	
Data Rate	DC	_	32	Gb/s	
SE Swing (differential			300	mV	0.3% THD at 1 <i>GHz</i>
signal is applied)			500	mV	0.9% THD at 1 <i>GHz</i>
CM Level	vcc-Swing/2 for DC input termination				
Data output ((q11p/q1	1n, q12	2p/q12n,	q21p/q2	1n, q22p/q22n)
Max peaking frequency	16		24	GHz	
Gain from Input	-3		+5	dB	Depending on SPI settings
CM Level	vcc-0.35		V	for DC output termination	
	Peak De	tector o	utput (pl	kd1, pkd	2)
Voltage range	1.65		2.88	V	For input swing control
	3.05		3.25	V	For LOS operation
Settling time	15		20	ns	
3-Wire Interface Port					
Clock frequency	0.1		50	MHz	
Input low logic level	vee	\	/ee+0.3	V	
Input high logic level	vcc-1.3	3	VCC	V	
Output low logic level	vee		/ee+0.2	V	
Output high logic level	vcc-0.3	3	VCC	V	
Input current			9	иA	For each input



ABSOLUTE MAXIMUM RATINGS

Caution: Exceeding the absolute maximum ratings shown in Table 3 may cause damage to this product and/or lead to reduced reliability. Functional performance is specified over the recommended operating conditions for power supply and temperature only. AC and DC device characteristics at or beyond the absolute maximum ratings are not assumed or implied. All min and max voltage limits are referenced to ground (assumed vee).

Table 3. Absolute Maximum Ratings

Parameter	Min	Max	Units
Main Supply Voltage (VCC)		3.6	V
Additional Supply Voltage (v5p0)		5.5	V
RF Input Voltage Swing (SE)		750	mV
Case Temperature		+85	°C
Storage Temperature	-40	+100	°C
Operational Humidity	10	98	%
Storage Humidity	10	98	%

PACKAGE INFORMATION

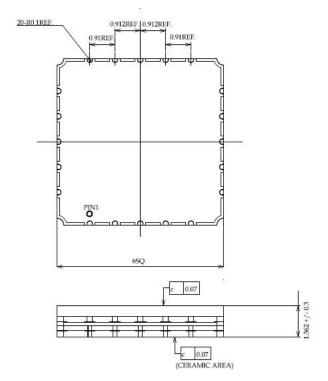
The chip die is housed in a custom, 44-pin CQFN package shown in Fig. 8. The package provides a center heat slug located on the back side of the package to be used for heat dissipation. ADSANTEC recommends using extreme caution when soldering this section to the board to avoid overheating. It should be connected to the **vcc** plain that is ground for the negative supply, or power for the positive supply.

The part's identification label is ASNT6153-KHM (more correct naming would be ASNT6153-KHS due to large cavity dimensions). The first 8 characters of the name before the dash identify the bare die including general circuit family, fabrication technology, specific circuit type, and part version while the 3 digits after the underscore represent the package's manufacturer, type, and pin out count.

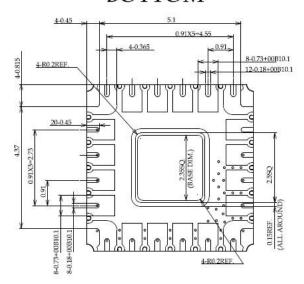
This device complies with Commission Delegated Directive (EU) 2015/863 of 4 June 2015 amending Annex II to Directive 2011/65/EU of the European Parliament and of the Council as regards the list of restricted substances (Text with EEA relevance) on the restriction of the use of certain hazardous substances in electrical and electronics equipment (RoHS Directive) in accordance with the definitions set forth in the directives for all ten substances.



TOP



BOTTOM



All Dimensions in mm

Fig. 8. CQFN44 Package Drawing (All Dimensions in mm)

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REVISION HISTORY

Revision	Date	Changes
1.4.2	04-2023	Corrected Package Drawing
1.3.2	04-2023	Corrected Package Drawing
1.2.2	03-2023	Corrected Pole 1 frequency
		Corrected v5p0 current consumption specification
		Corrected power consumption value
1.1.2	03-2022	Added note about package identification label
1.0.2	02-2022	Corrected Description
		Corrected labels in Fig. 3
		Added Table 1
		Corrected SPI signal naming
0.5.2	04-2021	Added SPI functions descriptions
		Added SPI timing diagram
0.4.2	03-2021	Added power supply diagrams
		Changed recommendation for the package soldering
0.3.2	12-2020	Corrected temperature specifications
0.2.2	12-2020	Corrected Absolute Maximum RF swing
		Corrected pkd1/2 terminal description
		Corrected Electrical Specifications table
0.1.2	12-2020	Corrected SPI description
0.0.2	12-2020	Preliminary release